

Density Functional Theory Study of surface properties of SnO₂ doped with nitrogen and chlorine for application in solar cells.

N NEKHWEVHA^a, N.E. MALUTA^{a,b}, R.R. MAPHANGA^{b,c}

^aDepartment of Physics, University of Venda, P/ Bag X 5050, Thohoyandou, 0950
^bNational Institute of Theoretical and Computational Sciences (NITheCS), Gauteng, South Africa
^cCouncil for Scientific and Industrial Research, P.O. Box 395, Pretoria, 0001
 nekhwevhalulu@gmail.com



INTRODUCTION

RESULTS AND DISCUSSIONS

❖ DSSCs are composed of four major components: a wide band gap SnO₂ semiconductor, a dye-sensitizer to absorb photons from the sun, an electrolyte that creates the interface with the semiconductor and a counter electrode carrying an electro-catalyst, which facilitates transfer of electrons to the electrolyte [1,2].

❖ In DSSCs, a semiconductor absorbs and facilitates transport of electron into the cathode material. Due to optical band gap slightly above 3 eV SnO₂ is only photoactive in the UV region of electromagnetic spectrum and an inefficient active in DSSC.

❖ Introduction of the impurities reduces the band gap of semiconductor and shift the absorption from UV to Vis and near infrared

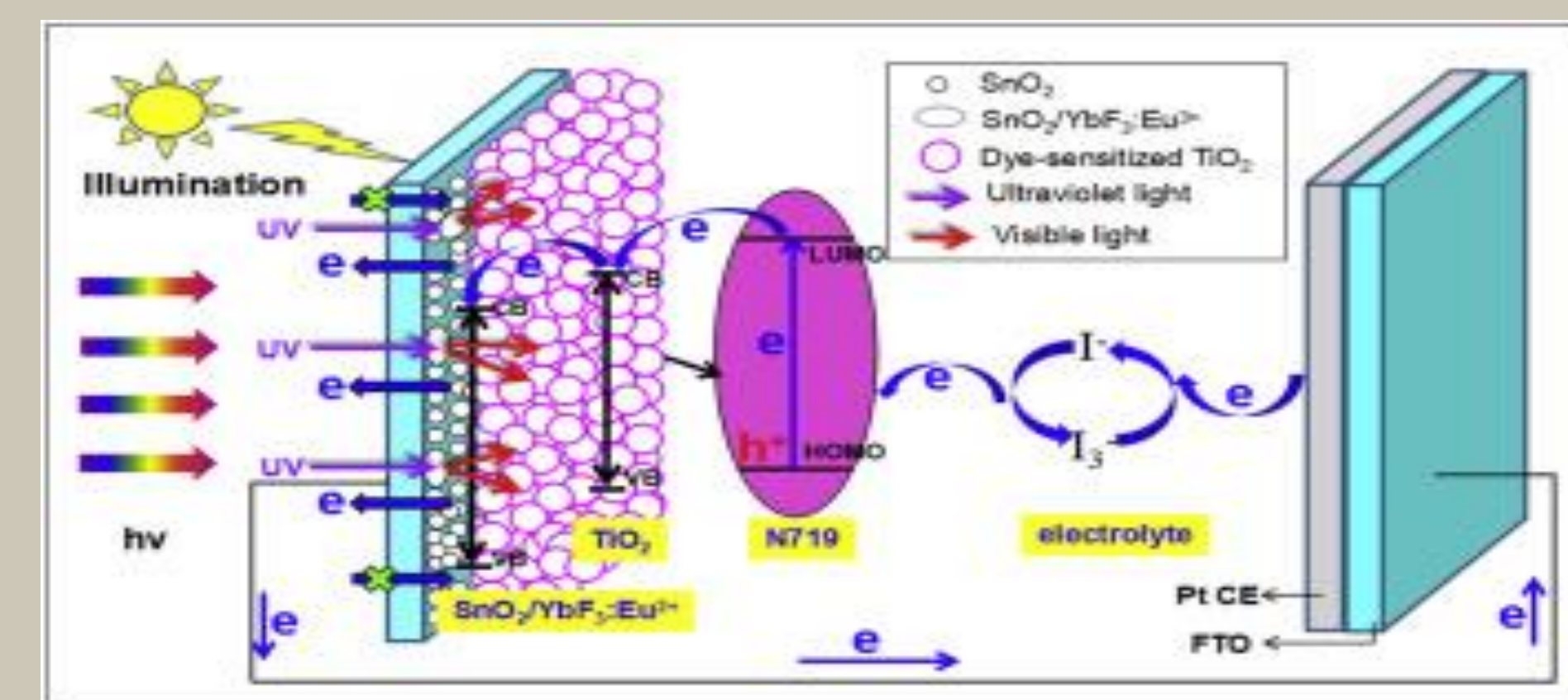


Figure 1: Operating principle of DSSC [3]

In this study, we carried out DFT study on the doped 2x2x2 supercell structure doped with Nitrogen and Chlorine. To understand the electronic and optical properties particularly the band structure, DOS and absorption of NaSnO₂, ClSnO₂ and CL-NSnO₂.

STRUCTURES

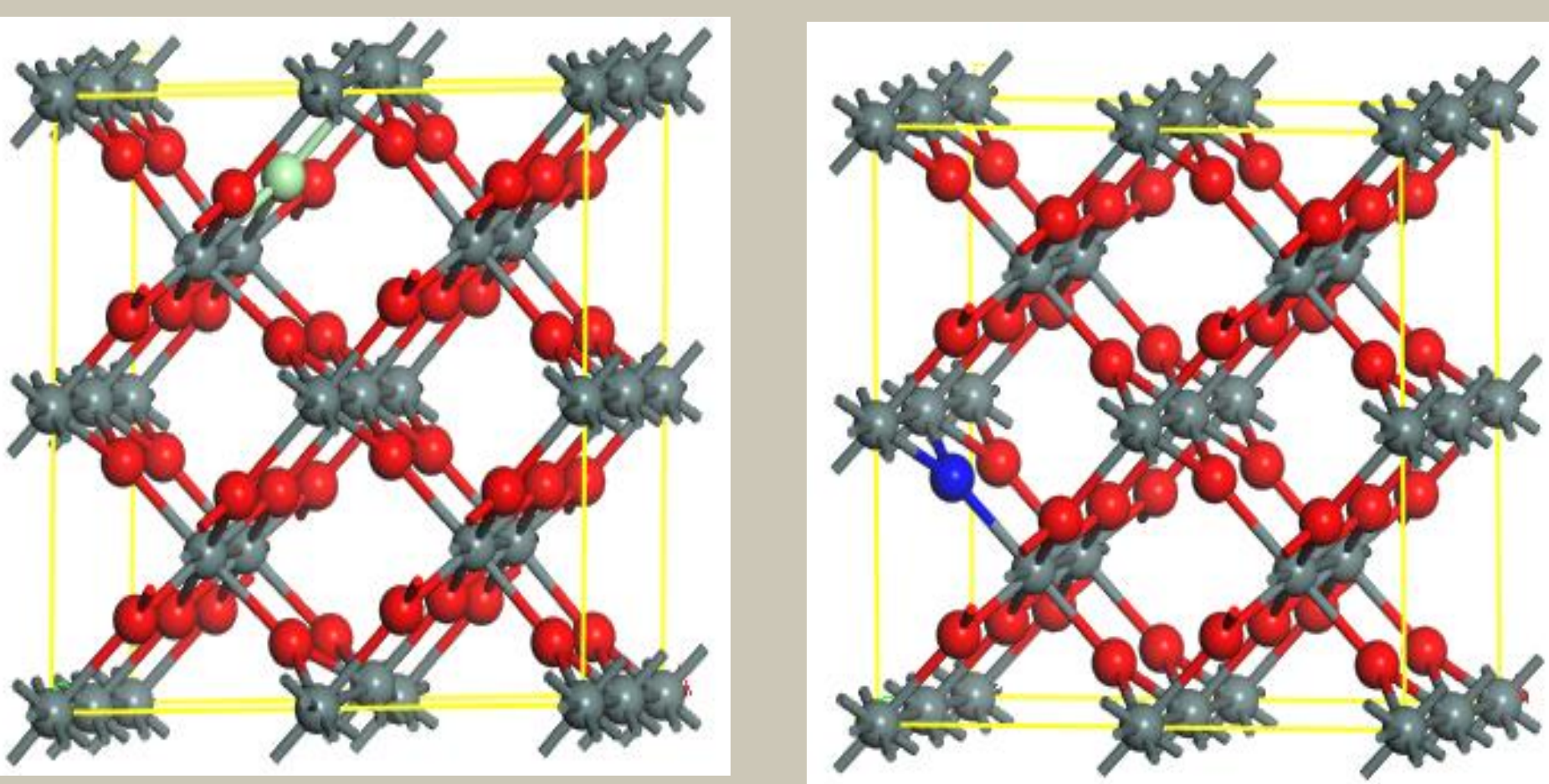
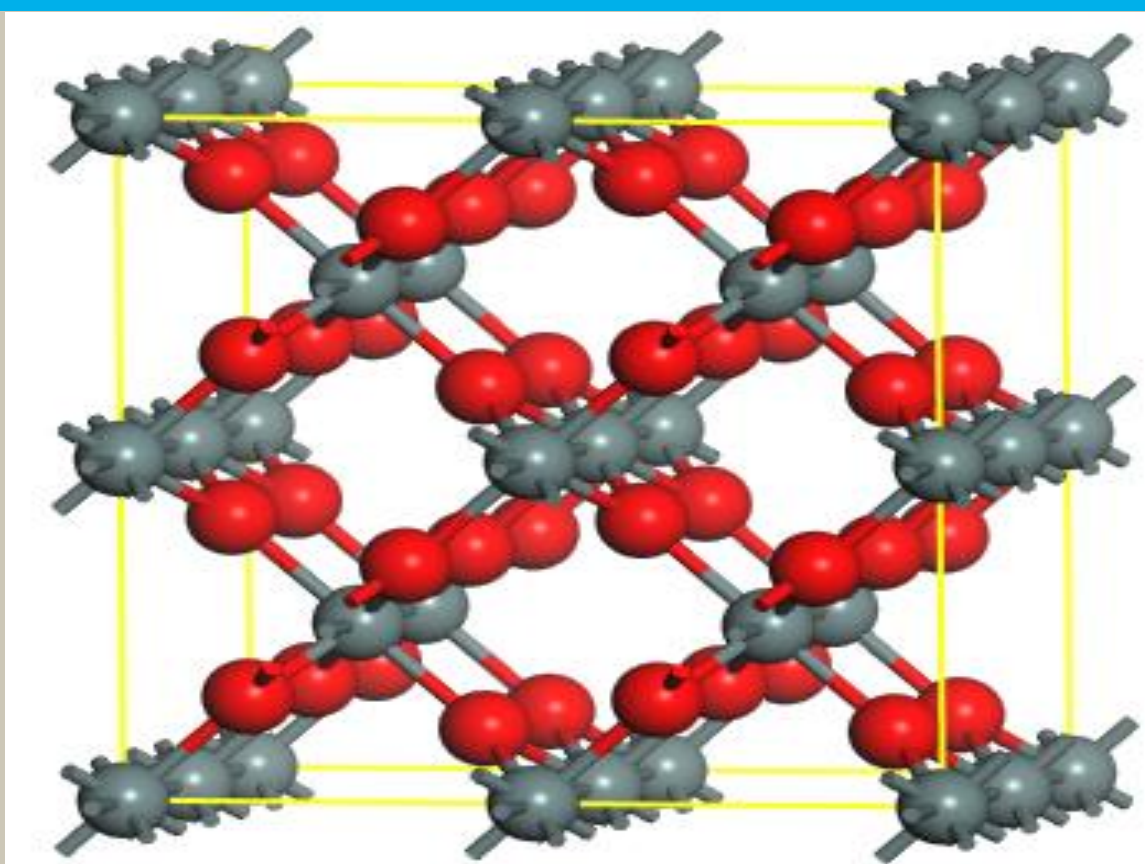


Figure 2: The supercell structure: pure SnO₂, Cl-SnO₂ and N-SnO₂ doped.

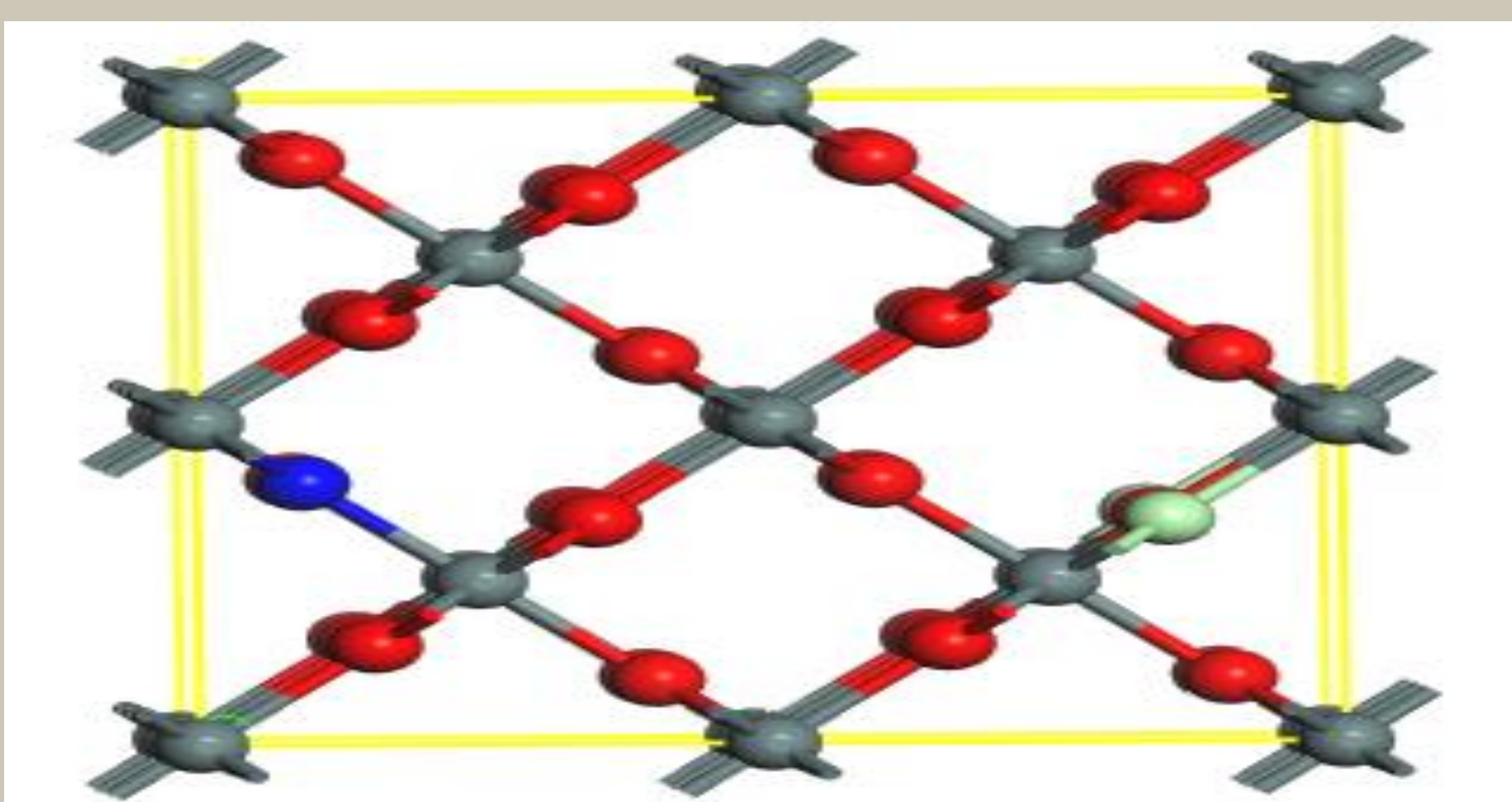


Figure 3: N-Cl-SnO₂ co-doping

Figure 2 and 3 shows the structure of supercell with red, grey, blue and green ball representing oxygen, tin, nitrogen, and chlorine respectively.

COMPUTATIONAL METHOD

➤ The structure of the SnO₂ was built using Material Studio package. The supercell was then built from the bulk structure to form SnO₂. It was optimized to minimize the convergence parameters (k points and cutoff energy), which were 4x4x6 and 650 eV respectively.

➤ The SnO₂ 2x2x2 supercell was optimized using the CASTEP module in BIOVA Materials Studio [4], and the electronic and optical properties were calculated using CASTEP code.

Band structure and density of state

The band structure and density of state are illustrated in figure 5 to figure 7. In these figures it can be seen that the bottom of conduction band and the top valence band are located at the G point in the brollouin zone. There is a high peak in the conduction band which is near the fermi level and is contributed by the orbital electrons of nitrogen and chlorine atom. The valence band is controlled by O-2p, and some few Cl-2p and Sn-5s state. We have some states of Cl-2p and Sn-5s which are dominant in the conduction band minimum. Few p-state of N atom can be seen in the conduction band, but far from the fermi level hence ignored. The introduction of the new state contrast the band gap of the system

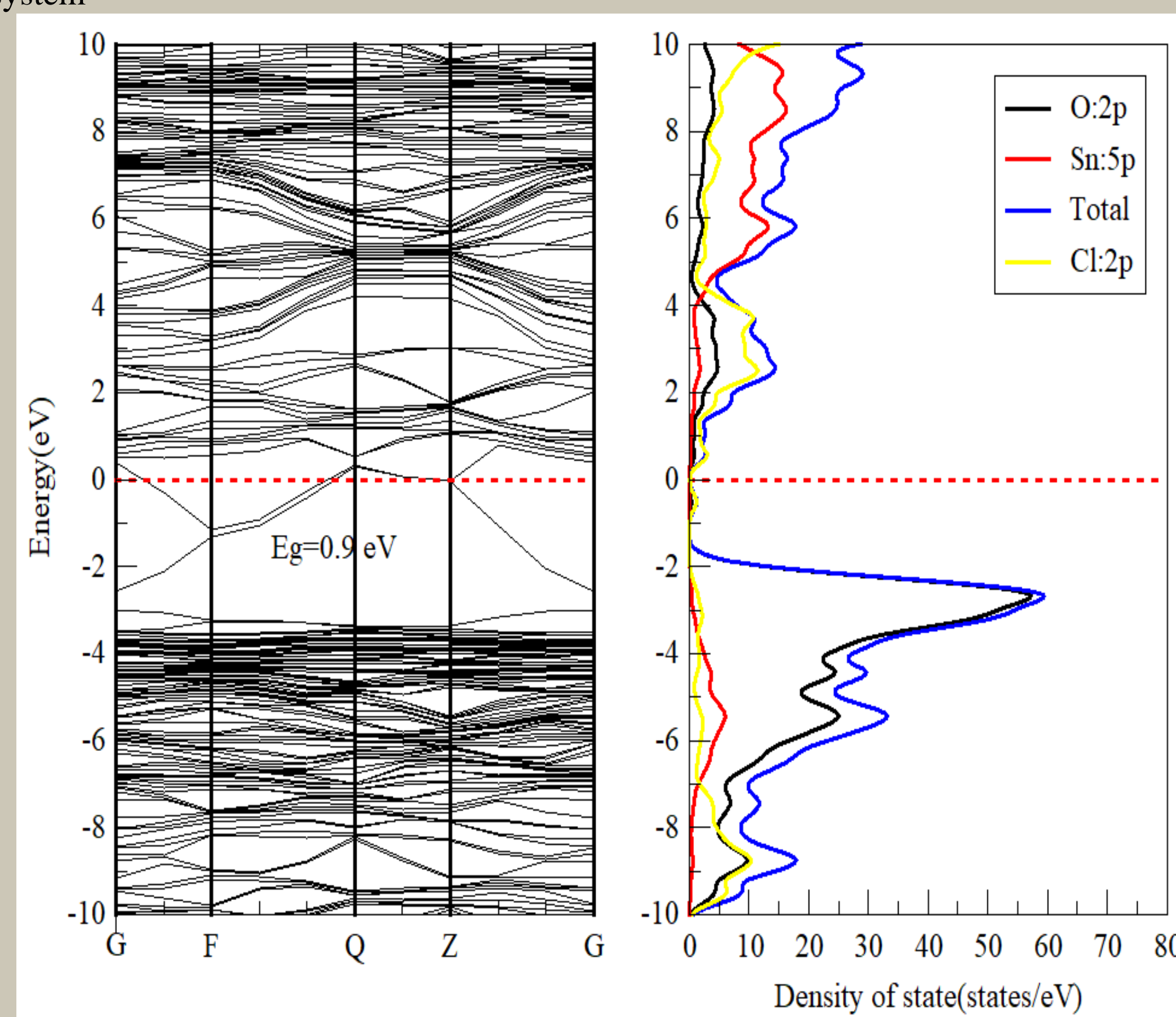


Figure 5: band structure and density of state of Cl-SnO₂

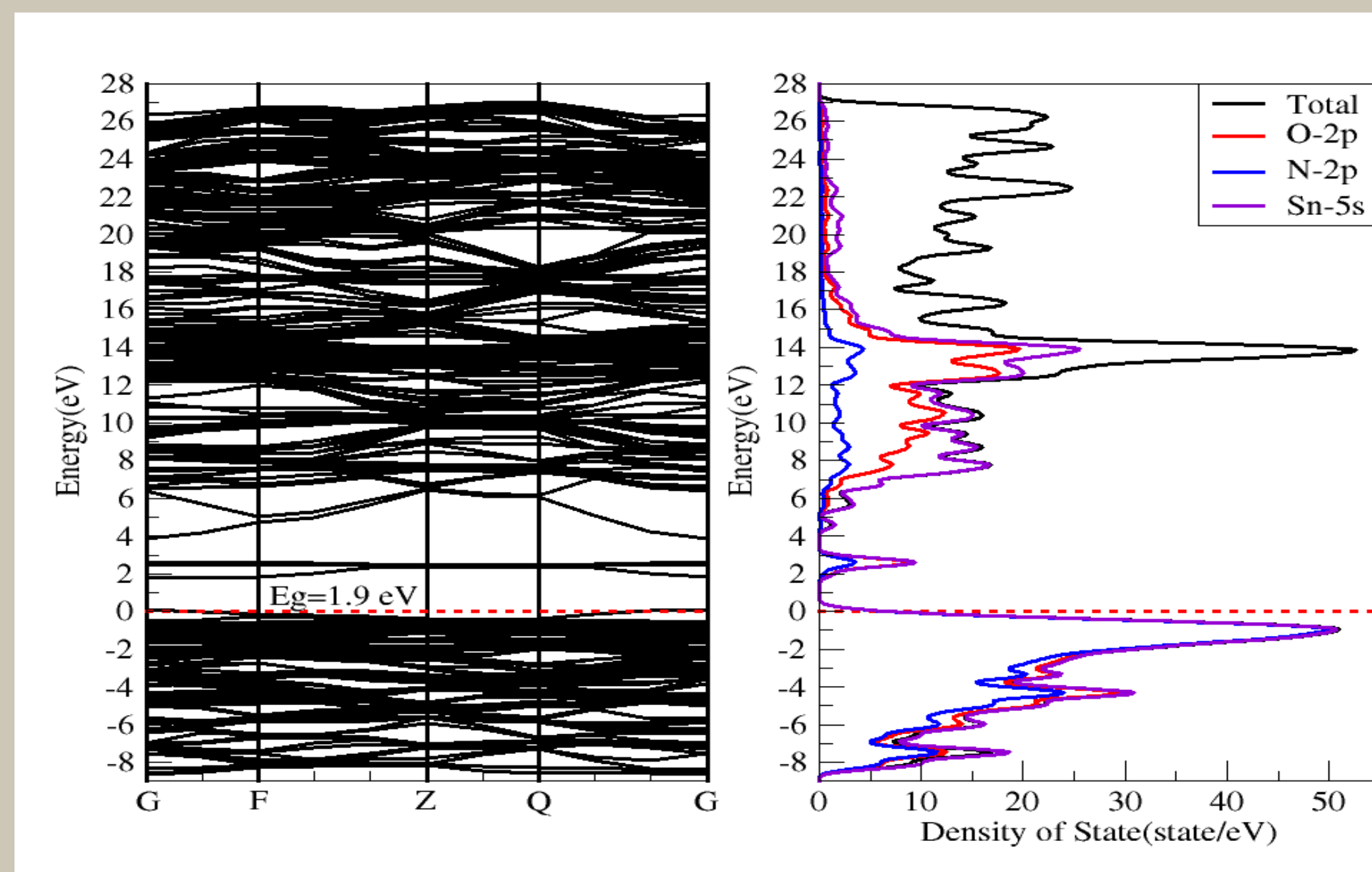


Figure 6: Band structure and density of state of N-SnO₂.

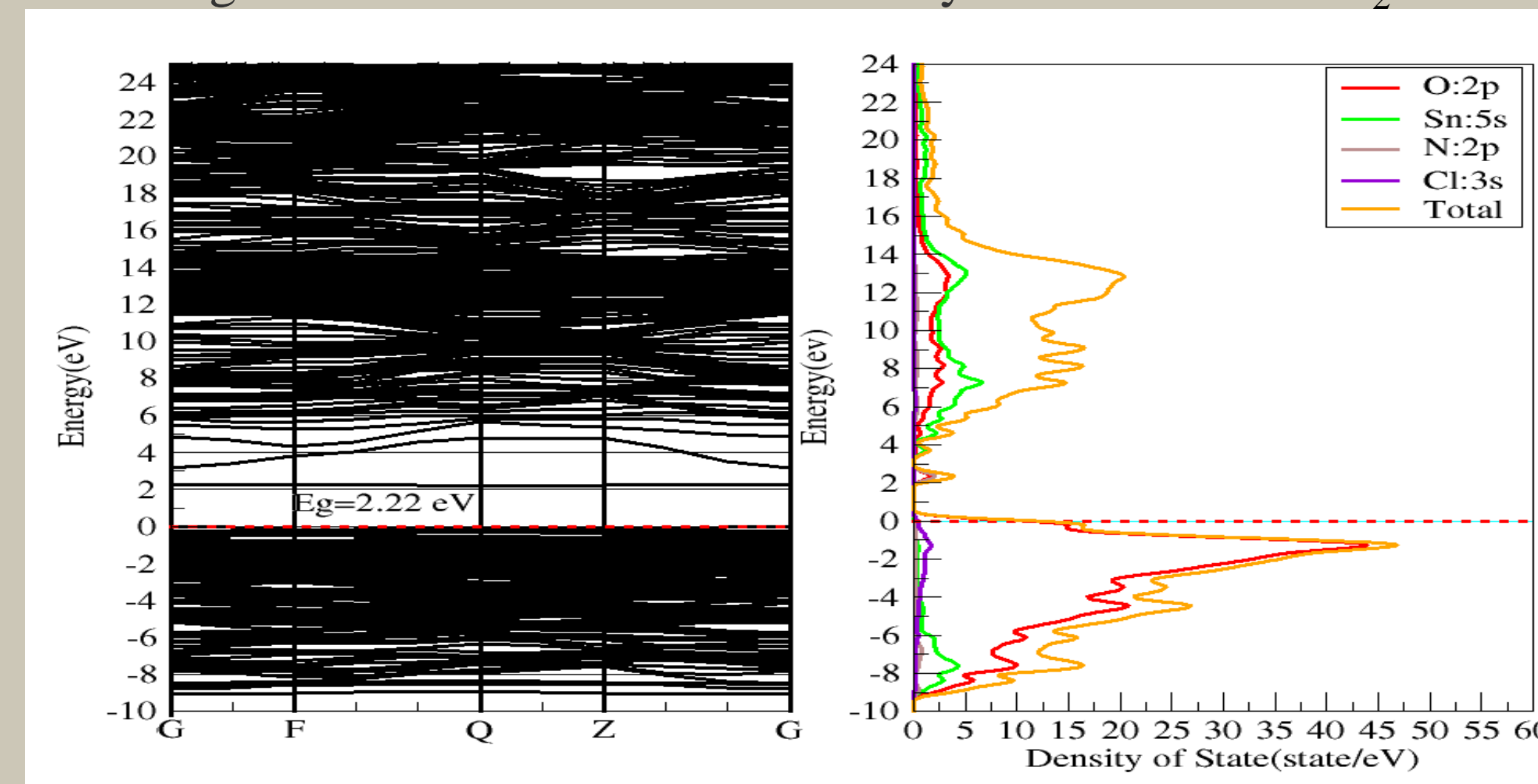


Figure 7: Band structure and density of state of Cl,N-SnO₂

Table 1: The lattice parameter of pure and doped SnO₂

Lattice parameter(Å)	a	b	c
Bulk	9.055	9.055	6.016
N	9.718	9.718	6.481
Cl	9.775	9.775	6.017
N-Cl	9.269	9.269	6.018
Literature[5]	9.349	9.349	6.299

The calculated equilibrium lattice parameters of pure and doped structure are shown in the table. From the results we know that the lattice parameter of the doped structure will increase due to the difference in atomic radius of different elements. This results in the expansion of the parameter a and c.

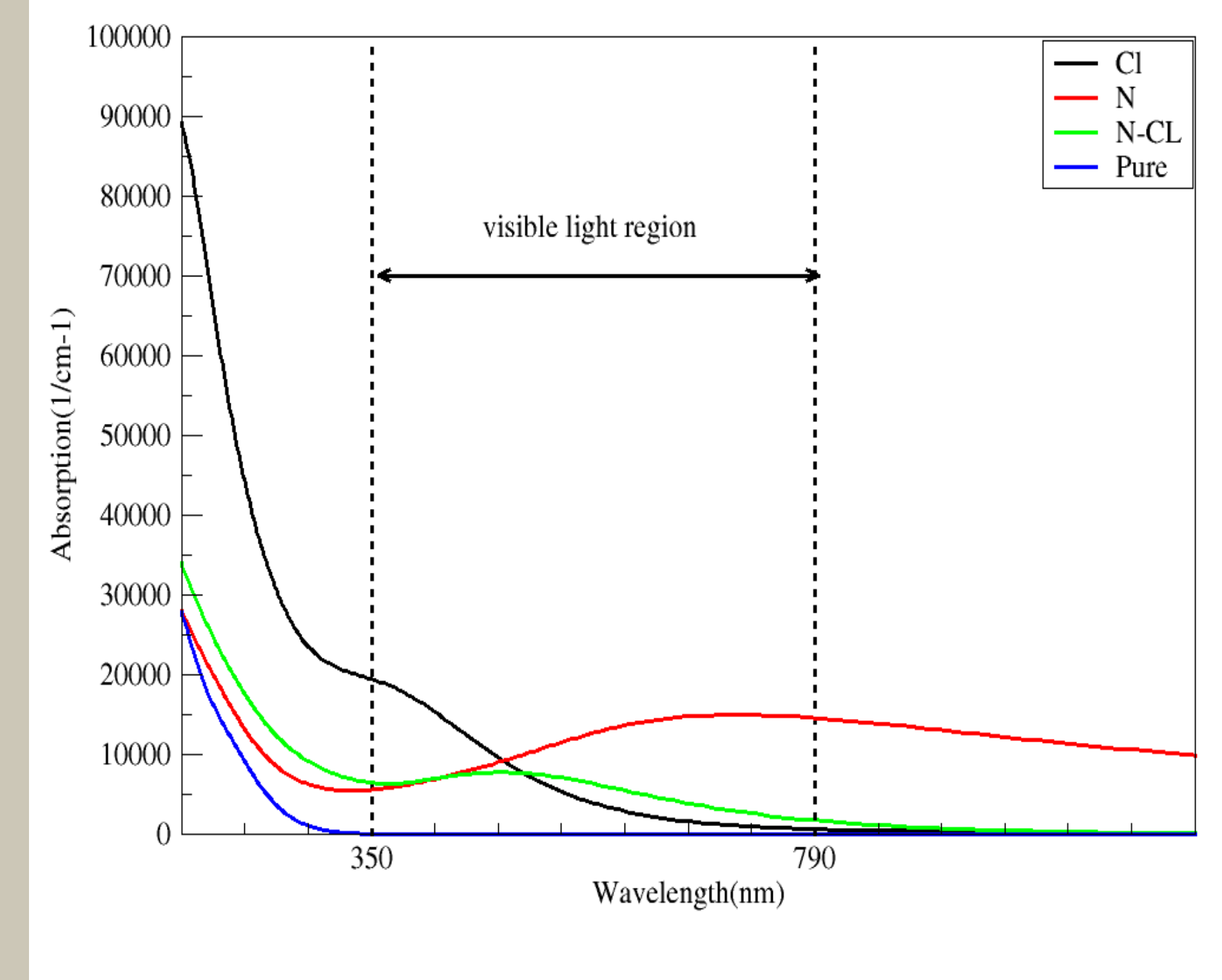


Figure 8: The absorption spectrum of pure and doped structure

The absorption of both doped and pure structure, it follows from these figures that pure SnO₂ shows no activity in the visible region and the doped SnO₂ shows higher absorption coefficient in the visible and in the infrared. When a narrow-band semiconductor material is added to the meso-porous SnO₂ electrode the light absorption in the visible increases and hence the light harvesting efficiency increases of the DSSC[3].

CONCLUSION

In this work, we have studied the effect of nitrogen and chlorine on electronic and optical properties of SnO₂. The electronic properties particularly the band gap and density of state was calculated, Undoped SnO₂ shows intense absorbance in the wavelength range below 390nm exhibiting a band gap of 3.57 eV. The band gap was found to decrease from 3.57 eV to 0.9,1.9,2.2 eV for chlorine doped, nitrogen doped and for co doping of nitrogen and chlorine respectively.

Our findings generally suggests that doping and co-doping SnO₂ with in nitrogen and chlorine introduces new state and contrast the band gap which results in shifting the absorption from UV to Vis and near infrared and is preferable for SnO₂ semiconductors having this features for application in DSSCs.

ACKNOWLEDGEMENTS

This work was financially supported through the NRF and the National institute for theoretical Physics (NITheCs). We would also like to thank the University of Venda for the opportunity to carry out this research and Centre for High performance Computing (CHPC) for using their computing facilities.

REFERENCES

1. Abodunrin, T.J., Obafemi, O., Boyo, A.O., Adebayo, T. and Jimoh, R. (2015). The Effect of Electrolyte on Dye Sensitized Solar Cells using Natural Dye from Mango (*M. indica L.*) Leaf as Sensitizer. *Advances in Materials Physics and Chemistry*, 5, 205-213.
2. Tong Zhu and Shang-Peng Gao (2014). The stability, electronic structure, and optical property of TiO₂ polymorphs. *American Chemical Society*, 118, 11385-11396.
3. Chou Cheun-Shii, Chou Feng-Cheng (2014). design and development of electronic and nano-structure for multifunctional working electrode in de sensitised solar cells.
4. Jason, K E (2011). Dye sensitised solar cells-working principles, challenges and opportunities. In solar cells dye sensitised devices. Tech
5. D Guo, C.Hu. First principle stud on the electronic structure and optical properties for SnO₂ with oxygen vacancy Applied Surface 258(2012)6987-6992